

# ST30120C STB30120C

# Technical Data Data Sheet N1369, Rev. A

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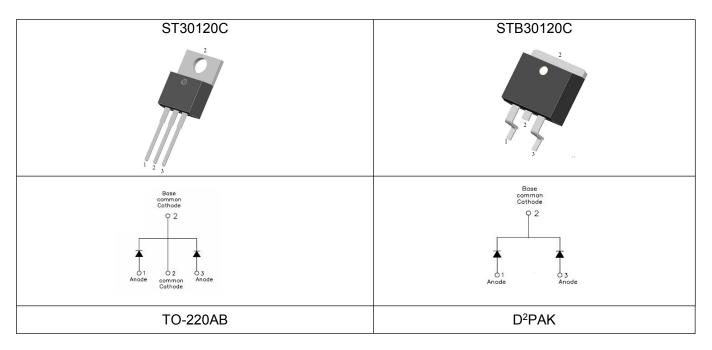
ST30120C/STB30120C SCHOTTKY RECTIFIER

# Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

### Features

- 150 °C T<sub>J</sub> operation
- Center tap configuration
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Trench MOS Schottky technology
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



# **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>	-		
Working Peak Reverse Voltage	VRWM		120	V
DC Blocking Voltage	V <sub>R</sub>			
Average Destified Forward Current		50% duty cycle @Tc=110°C,	15(Per Leg)	^
Average Rectified Forward Current	IF (AV)	rectangular wave form	30(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	200	А

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# **Electrical Characteristics:**

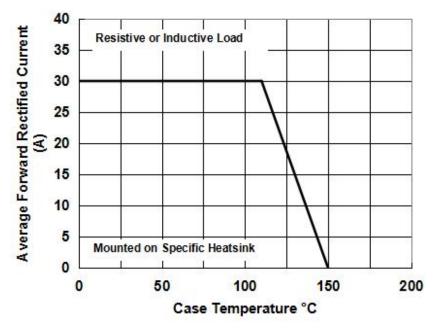
Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	* V <sub>F1</sub> @ 5A, Pulse, T <sub>J</sub> = 25°C @ 7.5A, Pulse, T <sub>J</sub> = 25°C @ 15A, Pulse, T <sub>J</sub> = 25°C		0.51 0.58 0.76	- - 0.97	V
	V <sub>F2</sub>	<ul> <li>@ 5A, Pulse, T<sub>J</sub> = 25°C</li> <li>@ 7.5A, Pulse, T<sub>J</sub> = 125°C</li> <li>@ 15A, Pulse, T<sub>J</sub> = 125°C</li> </ul>	0.46 0.52 0.64	- - 0.76	V
Reverse Current(Per Leg)*	I <sub>R1</sub>	<b>@</b> V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25°C	0.03	0.8	mA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R,</sub> T <sub>J</sub> = 125℃	6	50	mA
Junction Capacitance	Ст	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C f <sub>SIG</sub> = 1MHz	600	-	pF

\* Pulse width < 300 µs, duty cycle < 2%

# **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case(Per Leg)	$R_{\theta JC}$	DC operation	2.2	°C/W

# **Ratings and Characteristics Curves**





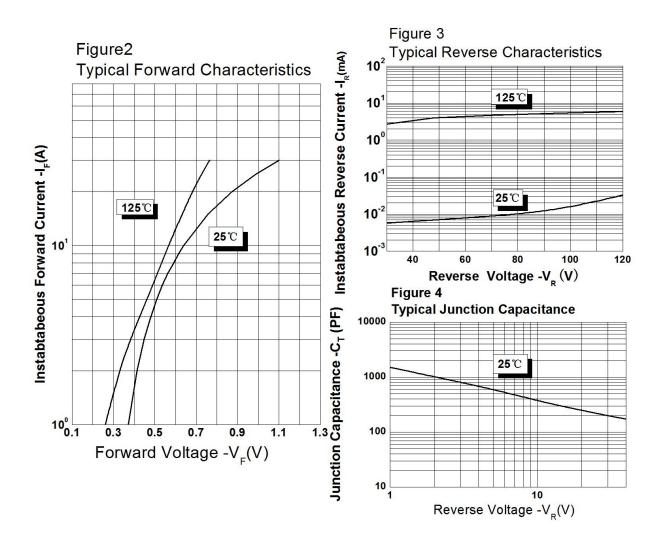
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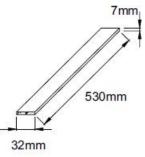


### **Tube Specification**

Device	Package	Weight	Shipping
ST30120C	TO-220AB	2.0	50pcs / tube
STB30120C	D <sup>2</sup> PAK	1.85	800pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

# Tube Specification(TO-220AB)



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# **Marking Diagram**



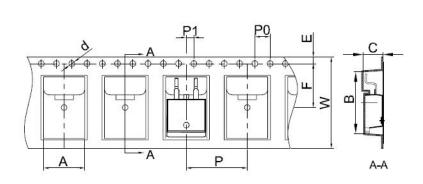


#### Where XXXXX is YYWWL

ST	= Device Type
В	= Package type
30	= Forward Current (30A)
120	= Reverse Voltage (120V)
С	= Configuration
SSG	= SSG
YY	= Year
WW	= Week
L	= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

# Carrier Tape Specification D2PAK



SYMBOL	Millimeters		
	Min.	Max.	
А	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
E	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	

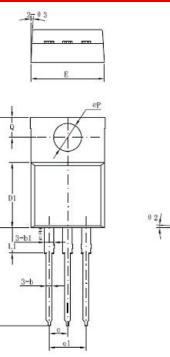


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# **Mechanical Dimensions TO-220AB**

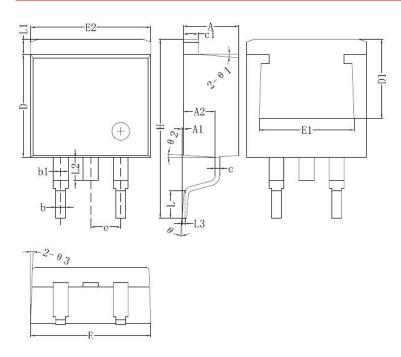


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Symbol	Dimensions in millimeters			
_	Min	Typical	Max	
A	4.42	4.57	4.72	
A1	1.17	1.27	1.37	
A2	2.52	2.69	2.89	
b	0.71	0.81	0.96	
b1	1.17	1.27	1.37	
С	0.31	0.38	0.61	
D	14.94	15.24	15.54	
D1	8.85	9.00	9.15	
E	10.01	10.16	10.31	
е		2.54		
e1	4.98	5.06	5.18	
H1	6.04	6.24	6.44	
L	12.7	13.56	13.80	
L1	3.56	3.5	3.96	
ΦΡ	3.74	3.84	4.04	
Q	2.54	2.74	2.94	
Θ1		7°		
Θ2		3°		
Θ3		4°		

# Mechanical Dimensions D<sup>2</sup>PAK



<u>A2</u>

Symbol	Dimensions in millimeters			
_	Min.	Typical	Max.	
A	4.47	4.70	4.85	
A1	0	0.10	0.25	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1	1.17	1.27	1.37	
С	0.31	0.38	0.61	
c1	1.17	1.27	1.37	
D	8.50	8.70	8.90	
D1	6.40			
E	10.01	10.16	10.31	
E1	7.6			
E2	9.98	10.08	10.31	
е		2.54		
Н	14.6	15.1	15.6	
L	2.00	2.30	2.74	
L1	1.12	1.27	1.42	
L2	1.30		2.20	
L3		0.25BSC		
е	0	-	8°	
e1		5°		
e2		<b>4</b> °		
e3		4°		

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